

# **Device Modeling Report**

COMPONENTS: Laser Diode  
PART NUMBER: SLD301V  
MANUFACTURER: SONY

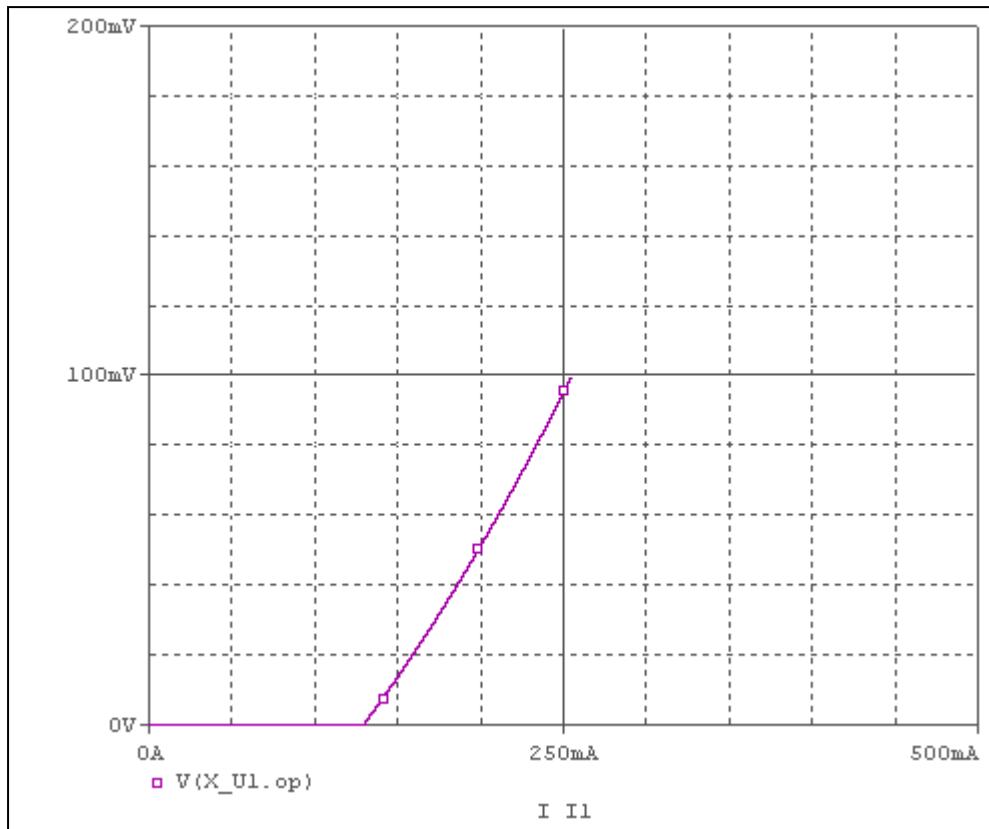


**Bee Technologies Inc.**

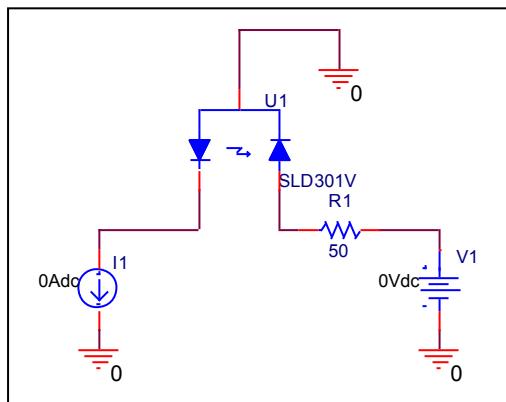
PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time

## Optical Output Power vs. Forward current characteristics

Circuit simulation result

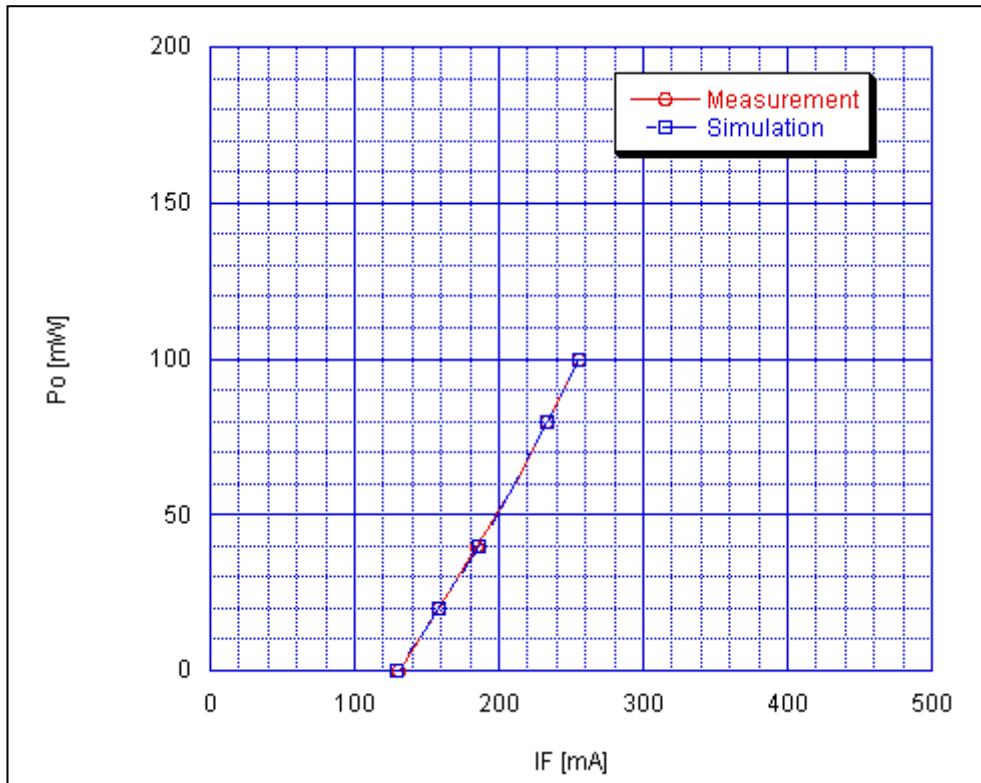


Evaluation circuit



## Comparison graph

Circuit simulation result

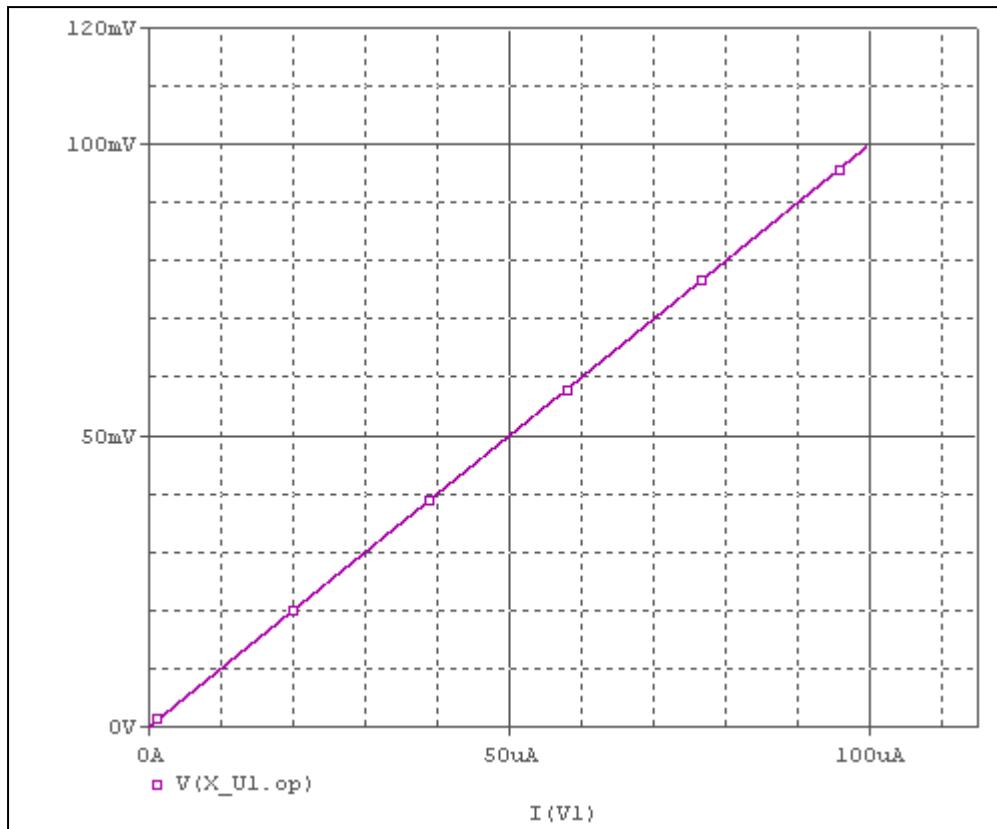


Simulation Result

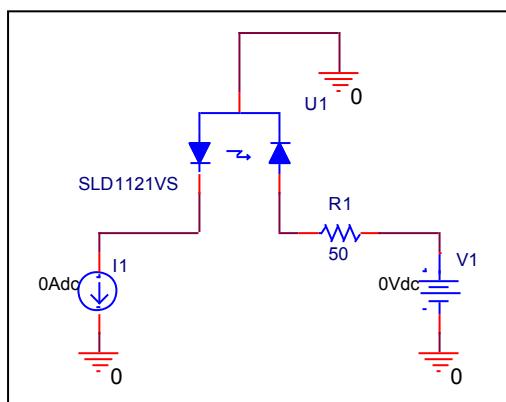
Po[mW]	IF[mA]		Error (%)
	Measurement	Simulation	
20	159	159.054	0.0339
40	185	185.901	0.487
60	210.6	210.610	0.004748
80	233	233.621	0.266524
100	255	255.172	0.067451

## Monitor Current vs. Optical Output Power characteristics

Circuit simulation result

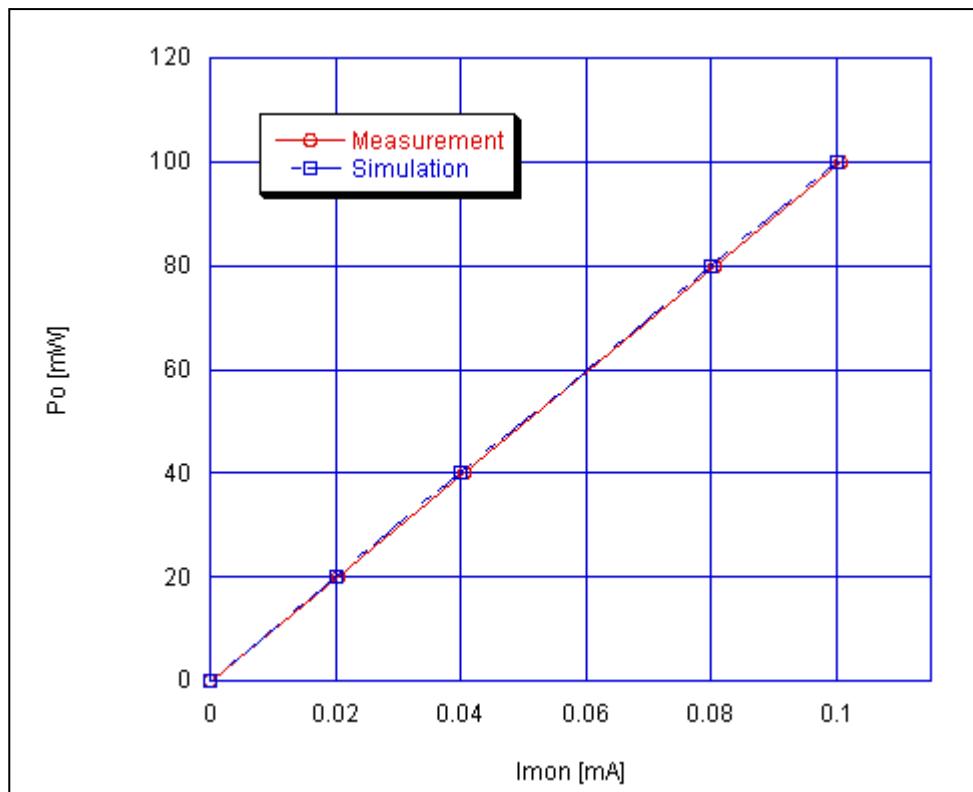


Evaluation circuit



## Comparison graph

Circuit simulation result



Simulation Result

Po[mW]	Imon[mA]		Error (%)
	Measurement	Simulation	
20	0.0205	0.02	2.439
40	0.0405	0.04	1.234
60	0.0605	0.06	0.826
80	0.0805	0.08	0.621
100	0.1005	0.1	0.498